

PNP Epitaxial Silicon Transistor

KSA1381

Features

- High Voltage: $V_{CEO} = -300 \text{ V}$
- Low Reverse Transfer Capacitance: $C_{re} = 2.3 \text{ pF}$ at $V_{CB} = -30 \text{ V}$
- Excellent Gain Linearity for Low THD
- High Frequency: 150 MHz
- Full Thermal and Electrical Spice Models are Available
- Complement to KSC3503
- This is a Pb-Free Device

Applications

- Audio, Voltage Amplifier and Current Source
- CRT Display, Video Output
- General Purpose Amplifier

ABSOLUTE MAXIMUM RATINGS (T_a = 25°C unless otherwise noted)

Symbol	Parameter	Ratings	Units
BV _{CBO}	Collector-Base Voltage	-300	W.
BV _{CEO}	Collector-Emitter Voltage	-300	//\v
BV _{EBO}	Emitter-Base Voltage	-5	(A)
I _C	Collector Current (DC)	-100	mA
I _{CP}	Collector Current (Pulse)	-200	mA
P _C	Total Device Dissipation, $T_C=25^{\circ}C$ $T_C=125^{\circ}C$	7 1.2	W
T_J , T_{STG}	Junction and Storage Temperature	-55~+150	°C

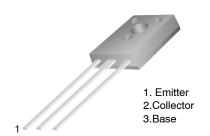
Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL CHARACTERISTICS (Note 1)

 $(T_a = 25^{\circ}C \text{ unless otherwise noted})$

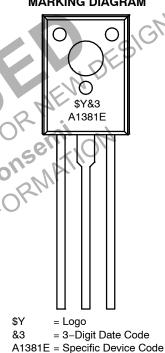
Symbol	Parameter	Max.	Units	
$R_{ heta JC}$	Thermal Resistance, Junction to Case	17.8	°C/W	

1. Device mounted on minimum pad size.



TO-126-3LD CASE 340AS

MARKING DIAGRAM



ORDERING INFORMATION

See detailed ordering and shipping information on page 2 of this data sheet.

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ELECTRICAL CHARACTERISTICS (Note 2) (T_a = 25°C unless otherwise noted)

Symbol	Characteristic	Test Condition	Min	Тур	Max	Unit
BV _{CBO}	Collector-Base Breakdown Voltage	$I_C = -10 \mu A, I_E = 0$	-300	_	_	V
BV _{CEO}	Collector-Emitter Breakdown Voltage	$I_{\rm C} = -1 \text{ mA}, I_{\rm B} = 0$	-300	_	_	V
BV _{EBO}	Emitter-Base Breakdown Voltage	$I_E = -10 \mu A, I_C = 0$	-5	_	_	V
I _{CBO}	Collector Cut-off Current	$V_{CB} = -200 \text{ V}, I_{E} = 0$	-	_	-0.1	μΑ
I _{EBO}	Emitter Cut-off Current	$V_{EB} = -4 \text{ V}, I_{C} = 0$	-	-	-0.1	μΑ
h _{FE}	DC Current Gain	$V_{CE} = -10 \text{ V}, I_{C} = -10 \text{ mA}$	100	=	200	
V _{CE} (sat)	Collector-Emitter Saturation Voltage	$I_C = -20 \text{ mA}, I_B = -2 \text{ mA}$	-	=	-0.6	V
V _{BE} (sat)	Base-Emitter Saturation Voltage	$I_C = -20 \text{ mA}, I_B = -2 \text{ mA}$	-	=	-1	V
f _T	Current Gain Bandwidth Product	$V_{CE} = -30 \text{ V}, I_{C} = -10 \text{ mA}$	-	150	_	MHz
C _{ob}	Output Capacitance	V _{CB} = -30 V, f = 1 MHz	-	3.1	_	pF
C _{re}	Reverse Transfer Capacitance	V _{CB} = -30 V, f = 1 MHz		2.3	- ~	pF

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

ORDERING INFORMATION

Part Number (Note 3, 4)	Marking	Package	Shipping	Remarks
KSA1381ESTU	A1381E	TO-126-3LD (Pb-Free)	1920 Units / Tube	HFE1 E Grade

^{3.} Affix "-S-" means the standard TO126 Package.(see package dimensions). If the affix is "-STS-" instead of "-S-", that r TO126 package.
4. Suffix "-TU" means the tube packing, The Suffix "TU" could be replaced to other suffix character as packing method. 3. Affix "-S-" means the standard TO126 Package (see package dimensions). If the affix is "-STS-" instead of "-S-", that mean the short-lead

^{2.} Pulse Test: Pulse Width ≤ 300 μs, Duty Cycle ≤ 2%

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TYPICAL CHARACTERISTICS

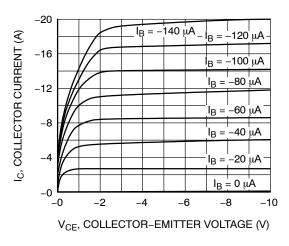


Figure 1. Static Characteristic

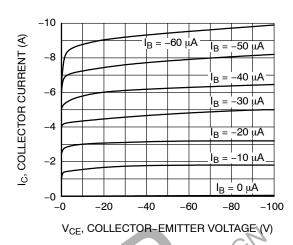


Figure 2. Static Characteristic

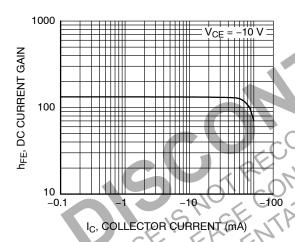


Figure 3. DC Current Gain

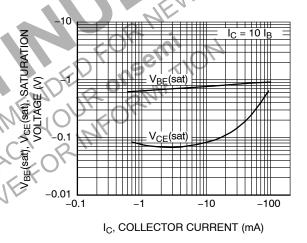


Figure 4. Base–Emitter Saturation Voltage Collector–Emitter Saturation Voltage

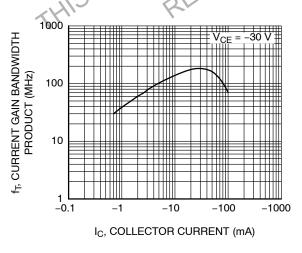


Figure 5. Current Gain Bandwidth Product

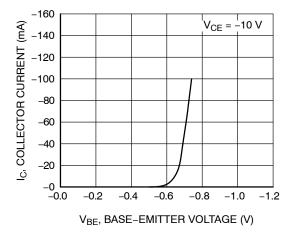


Figure 6. Base-Emitter On Voltage

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TYPICAL CHARACTERISTICS (Continued)

100

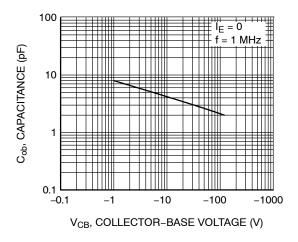


Figure 7. Collector Output Capacitance

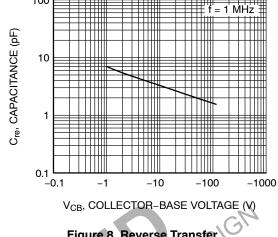
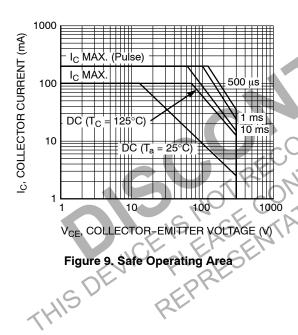


Figure 8. Reverse Transfer Capacitance



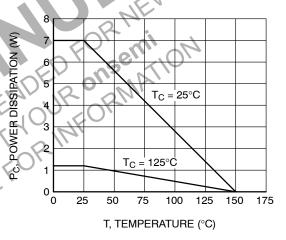
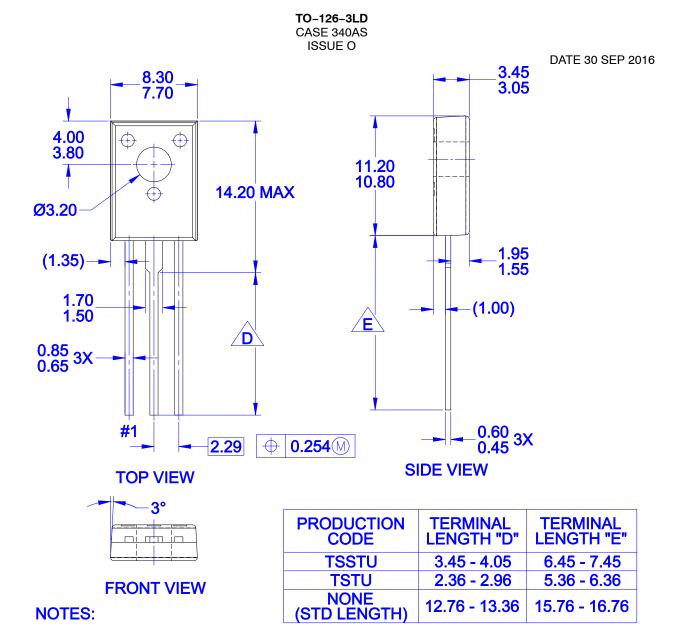


Figure 10. Power Derating





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- B. ALL DIMENSIONS ARE IN MILLIMETERS
- C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR PROTRUSIONS



E FOR TERMINAL LENGTH "E", REFER TO TABLE

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